



Description

The TD101X series combine an AlGaAs infrared emitting diode as the emitter which is optically coupled to a silicon planar phototransistor detector in a plastic LSO package with the robust coplanar double mold structure. TD101X series provide the most stable isolation feature.

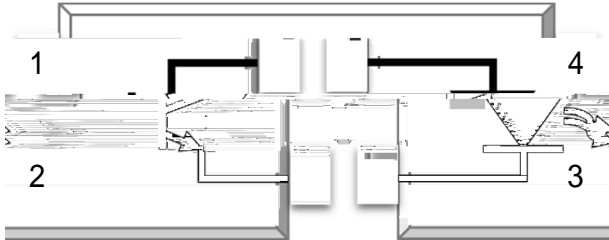
Features

- High isolation (000) * +S
- Temperature flexibility available see order information
- D, input with transistor output
- Operating temperature range . ((/ , to 110 / ,
- $I_{SO} \le 1A$, , compliance
- +SL class 1
- Regulatory Approvals
 - 2L . 2L1(33)
 -)D1 . 14503!3.(. (6)D1077!. (8
 - , 9 , : G ; !< !=#1% G ; 77<7

Applications

- Switch mode power supplies
- Programmable controllers
- Household appliances
- Office equipment

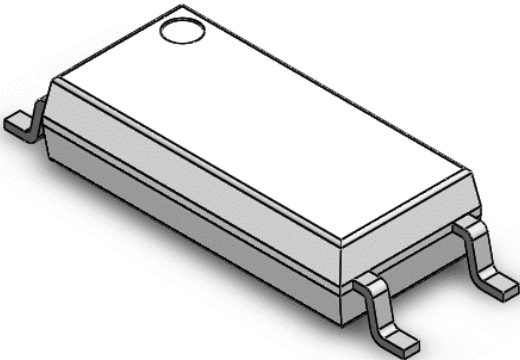
SCHEMATIC



PIN DEFINITION

	1. Anode
	2. Cathode
	3. Emitter
	4. Collector

PAC A ! E O " T # I N E





A ' SO# " TE MA (IM " M) ATIN ! S				
A * A + 1 T1 *	S@+ ; OL) AL21	24AT	4OT1
A4 2T				
Borward , urrent	AB	50	mA	
ea" Borward , urrent	AB	1	A	1
* e&erse) oltage) *	5)	
Anput ower Dissipation	A	100	m\$	
O2T 2T				
, ollector . 1mitter) oltage) , 10	70)	
1mitter . , ollector) oltage) 1 , 0	3)	
, ollector , urrent	A ,	(0	mA	
Output ower Dissipation	o	1(0	m\$	
, O+ +O4				
Total ower Dissipation	tot	?(0	m\$	
Asolation) oltage) iso	(000) rms	?
Operating Temperature	Topr	. ((C110	/ ,	
Storage Temperature	Tstg	. ((C1?(/ ,	
Soldering Temperature	Tsol	?50	/ ,	

Note 1. 100µs pulse, 100 ! "#e\$uenc%

Note 2. A& 'o# 1 ()nute, R. . * +0 , -0.



ELECTRICAL CHARACTERISTICS at Ta=25°C							
Symbol	Unit	Min	Typ	Max	Test Conditions	Notes	Ref
Forward Voltage	V _F	-	1.5	-	I _F = 10 mA, I _R = 0		
Reverse Current	I _R	-	10	-	V _R = 5 V, I _F = 0		
Input Capacitance	C _{in}	-	0	-	f = 1 kHz, V _R = 0 V		
Collector Current	I _C	-	-	100	V _{CE} = 5 V, I _B = 10 mA		
Collector-Emitter Saturation Voltage	V _{CE(sat)}	-	0.7	-	I _C = 10 mA, I _B = 10 mA		
Emitter-Emitter Saturation Voltage	V _{EE(sat)}	-	0.3	-	I _C = 10 mA, I _B = 10 mA		
Collector-Emitter Breakdown Voltage	V _{CE(BR)}	-	-	5	I _C = 10 mA, I _B = 0		
Collector-Emitter Saturation Current	I _{CE(sat)}	-	0.1	-	V _{CE} = 5 V, I _B = 10 mA		
Isolation Resistance	R _{ISO}	10 ¹¹	10 ¹¹	-	V _R = 50 V, I _F = 0		
Bloating Capacitance	C _{AO}	-	0	1	f = 1 kHz, V _R = 0 V		
Turn-off Frequency	f _{off}	-	70	-	V _R = 5 V, I _C = 10 mA, I _B = 0		
Response Time (t _{rise})	T _r	-	-	17	V _R = 5 V, I _C = 10 mA, I _B = 0		
Response Time (t _{fall})	T _f	-	-	5	V _R = 5 V, I _C = 10 mA, I _B = 0		

Note 1. V_F = 1.2-1.1 V
 Note 2. V_{CE(sat)} = 0.1 V



CHARACTERISTICS - ES

Fig. 1 Forward Current vs. Ambient Temperature

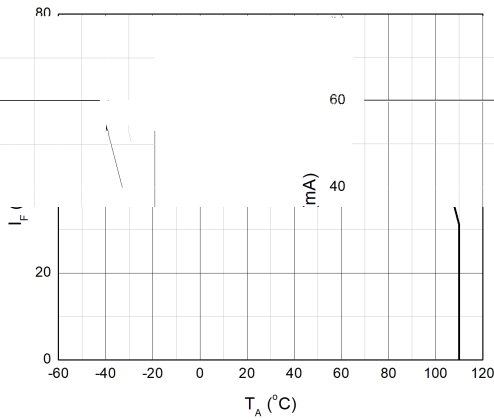


Fig. 2 Collector Power Dissipation vs. Ambient Temperature

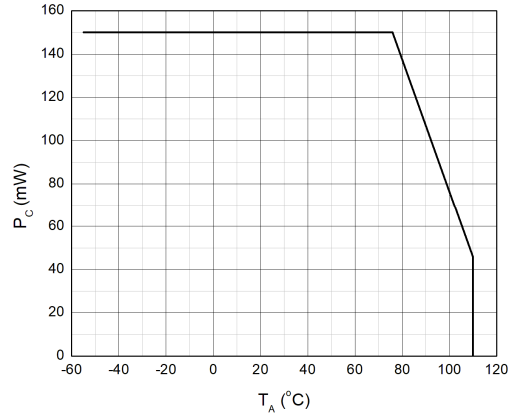


Fig. 3 Forward Current vs. Forward Voltage

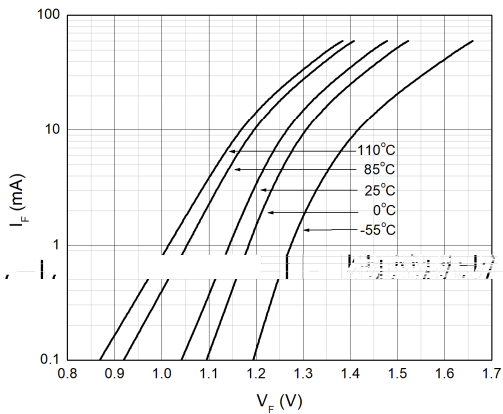


Fig. 4 Collector Dark Current vs. Ambient Temperature

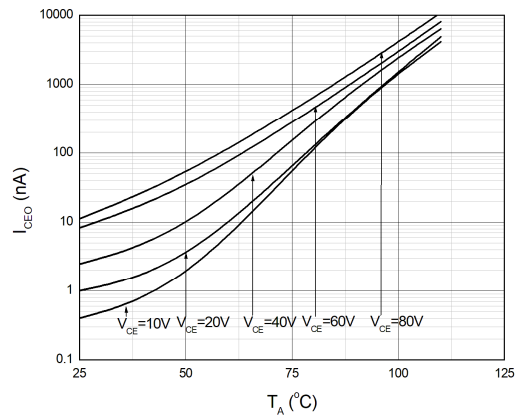


Fig. 5 Collector Current vs. Collector-Emitter Voltage

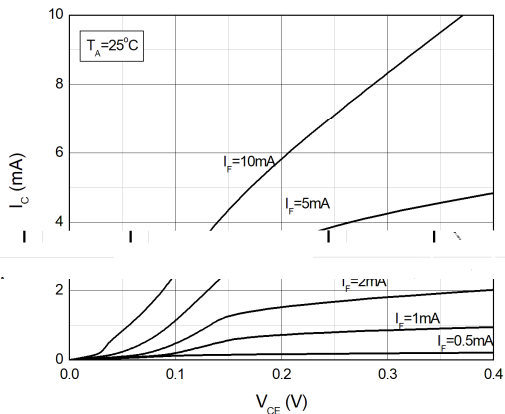
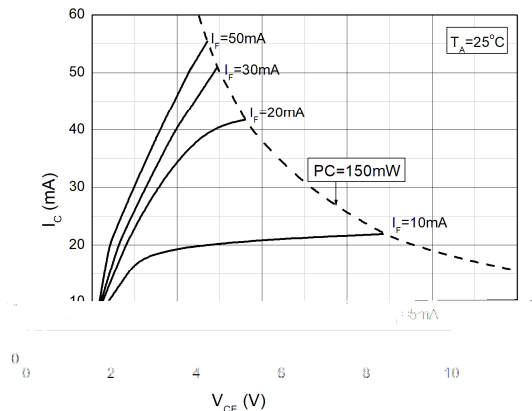


Fig. 6 Collector Current vs. Collector-Emitter Voltage



CHARACTERISTIC CURVES

Fig. 5 Normalized Current Transfer Ratio vs. Forward Current

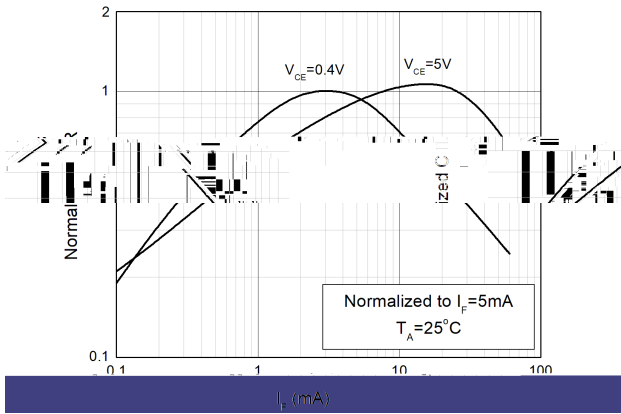


Fig. 8 Normalized Current Transfer Ratio vs. Ambient Temperature

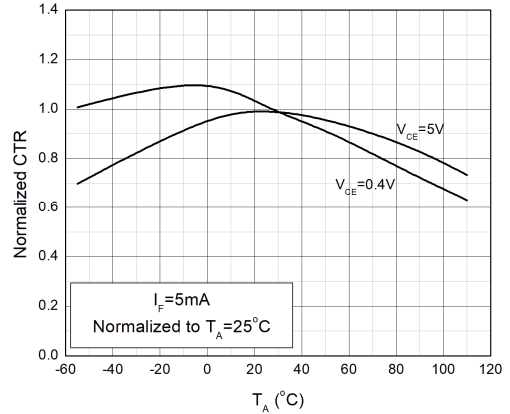


Fig. 9 Collector-Emitter Saturation Voltage vs. Ambient Temperature

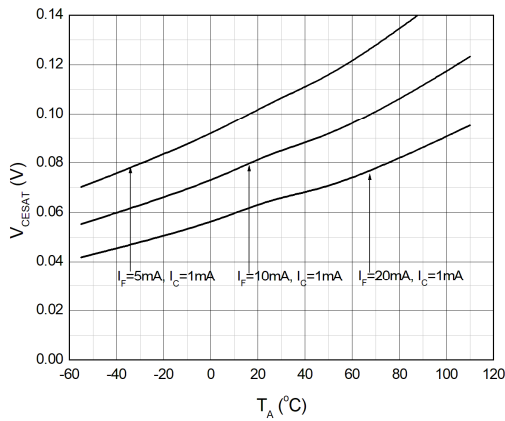


Fig. 10 Switching Time vs. Load Resistance

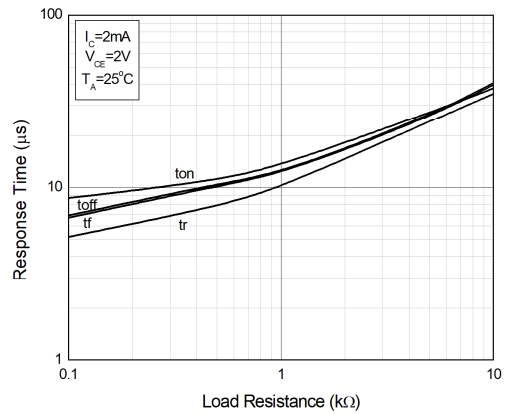
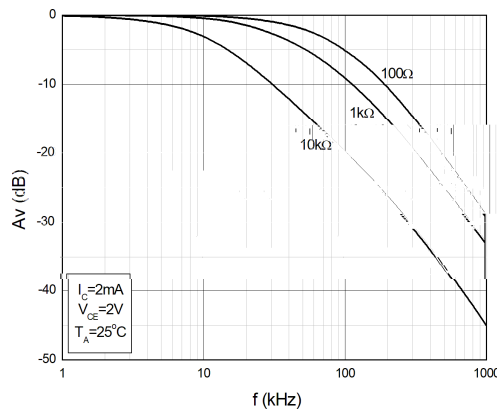


Fig. 11 Frequency Response



TEST CIRCUITS

Fig. 12 Test Circuit of Forward Time

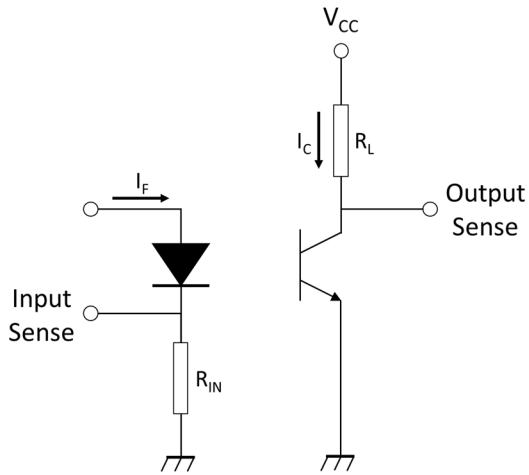


Fig. 13 Characteristic of Forward Time

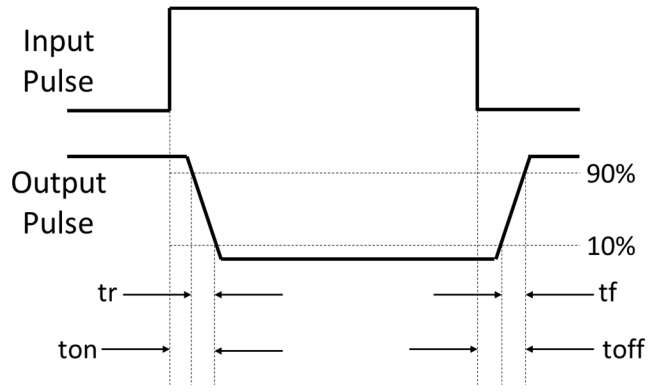
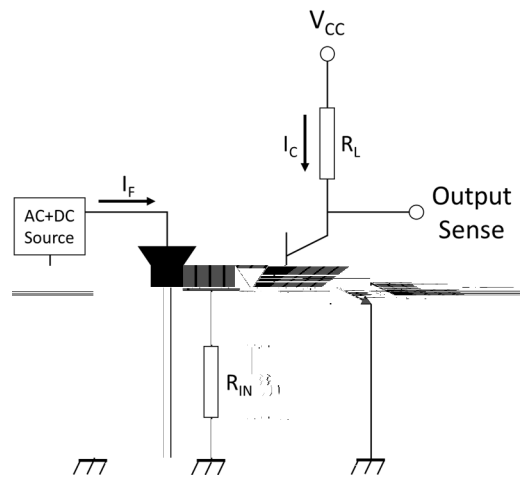
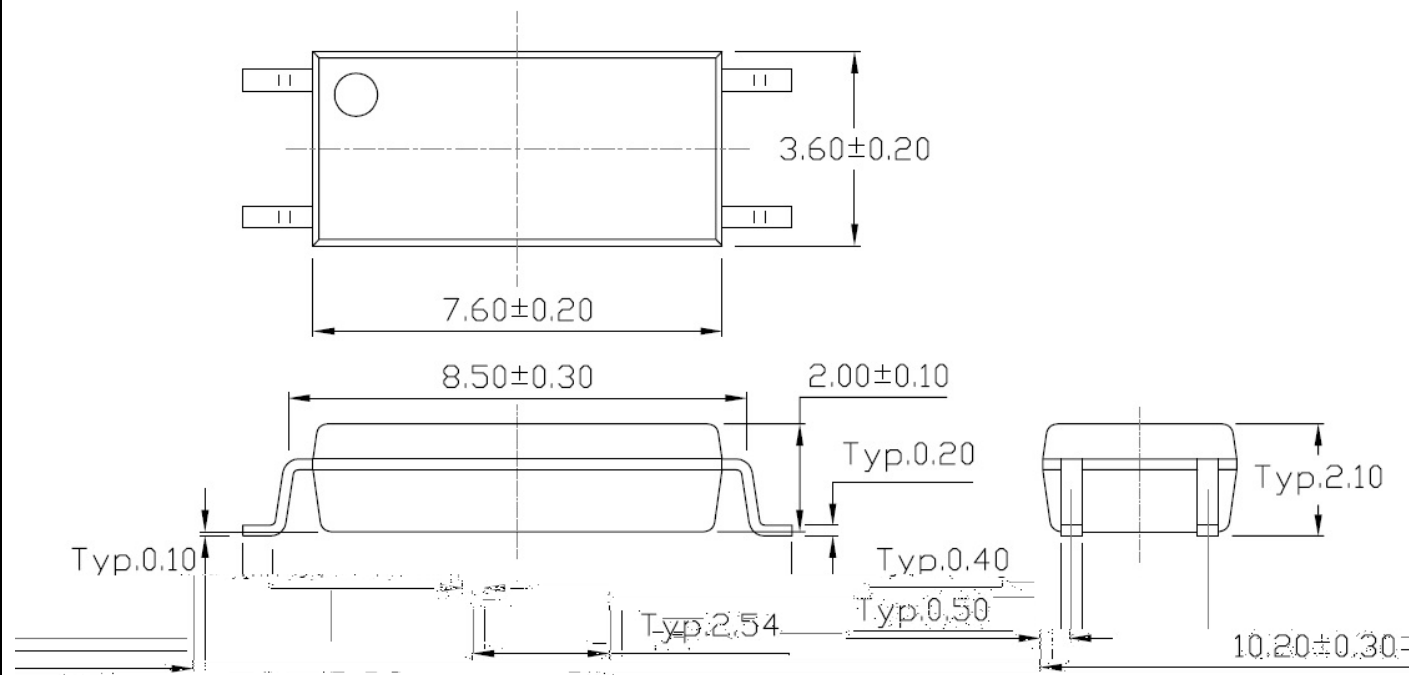


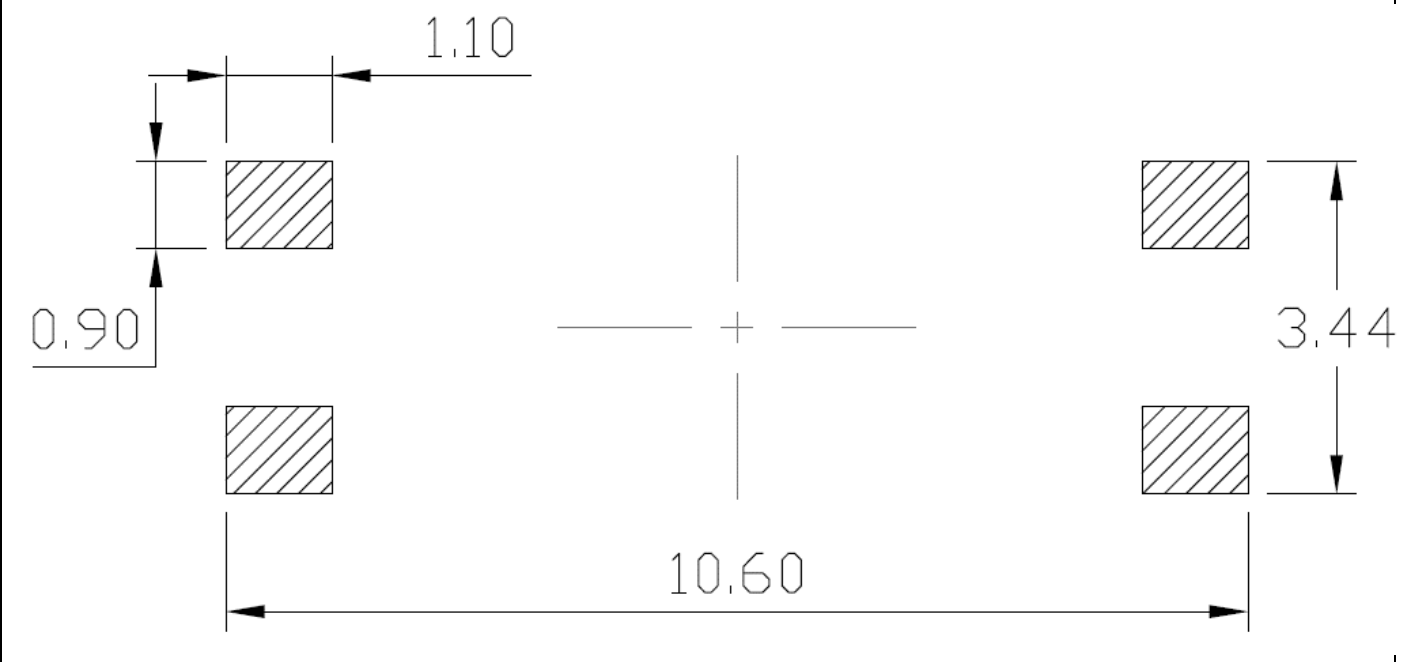
Fig. 14 Test Circuit of Reverse Time



PAC A ! E DIMENSIONS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=

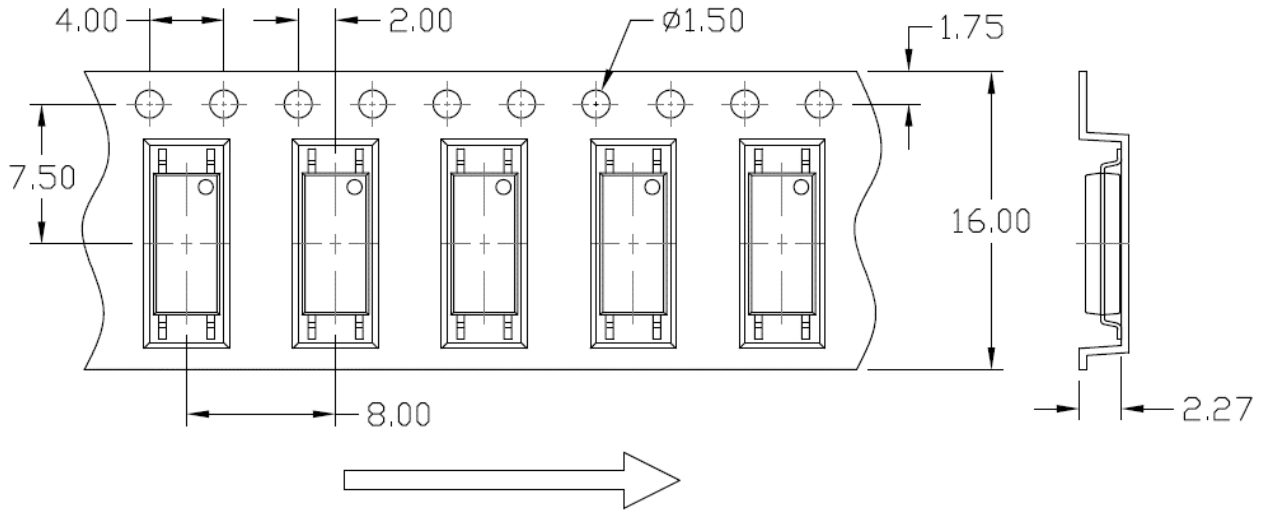


) ECOMMENDED SO#DE) MAS (Dimension\$ in mm & nle\$\$ other / i\$e \$tated=

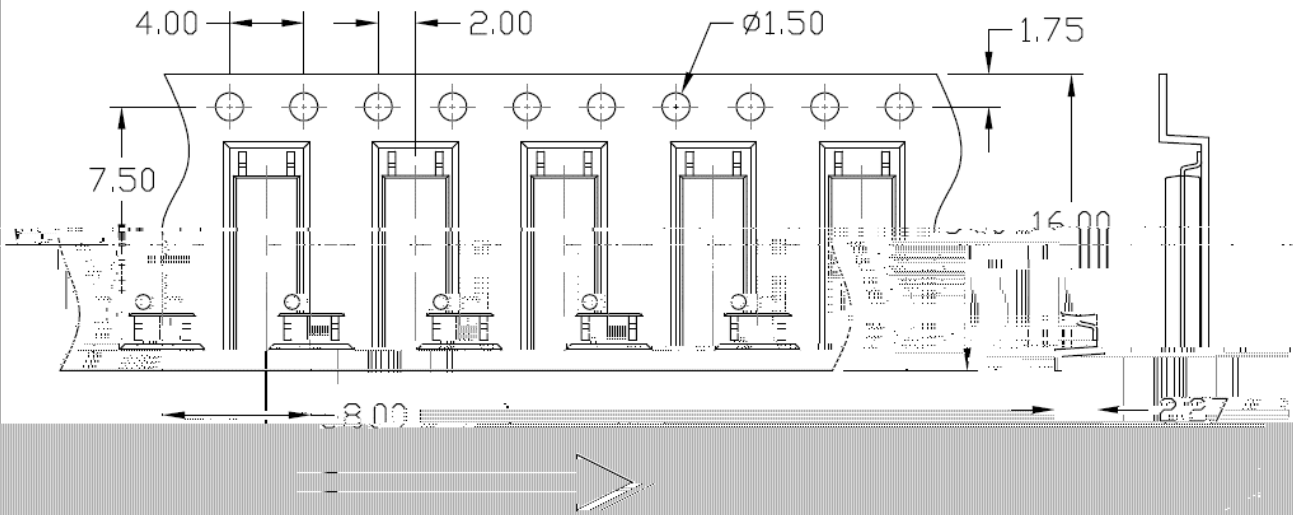


CA)) IE) TAPE SPECIFICATIONS (Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1

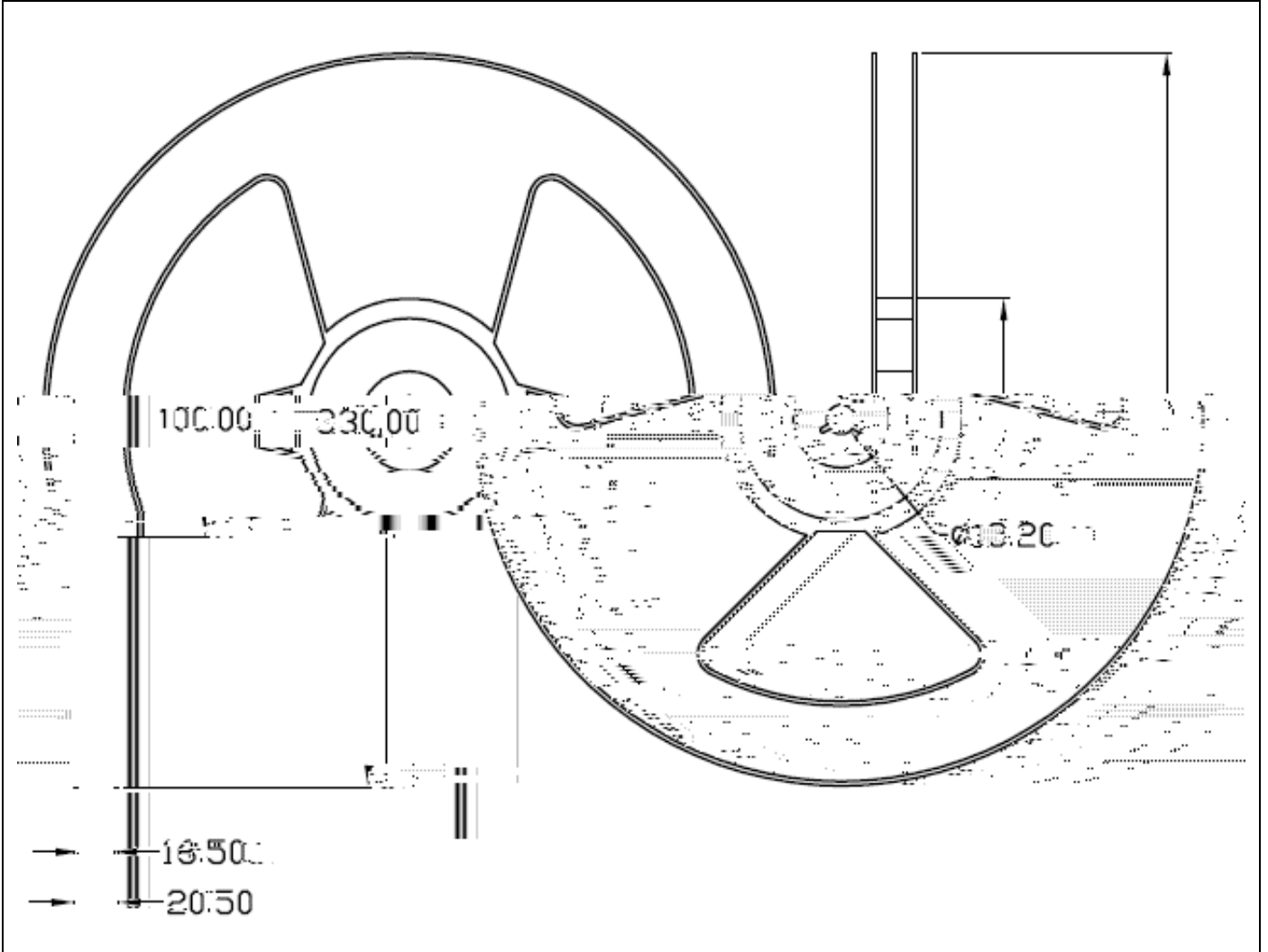


O%tion T2



EE# SPECIFICATIONS (Dimension\$ in mm &nle\$\$ other / i\$e \$tated=

O%tion T1 > T2





PRODUCT SPECIFICATIONS

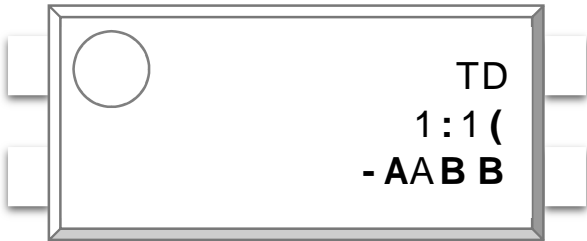
Inner Diameter

23 W 3 * /-cm 3 /-cm 3 -.9cm

Outer Diameter


OPTIONAL AND MAIN INFORMATION

MAIN INFORMATION

	<p>TD @ Company Abbr.</p> <p>1:1(@ Part Number)an2</p> <p>- @ -DE Option</p> <p>A @ Fiscal Year</p> <p>A @ Manufacturing . Code</p> <p>BB @ B or B2</p>
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OPTIONAL INFORMATION

FEATURE INFORMATION

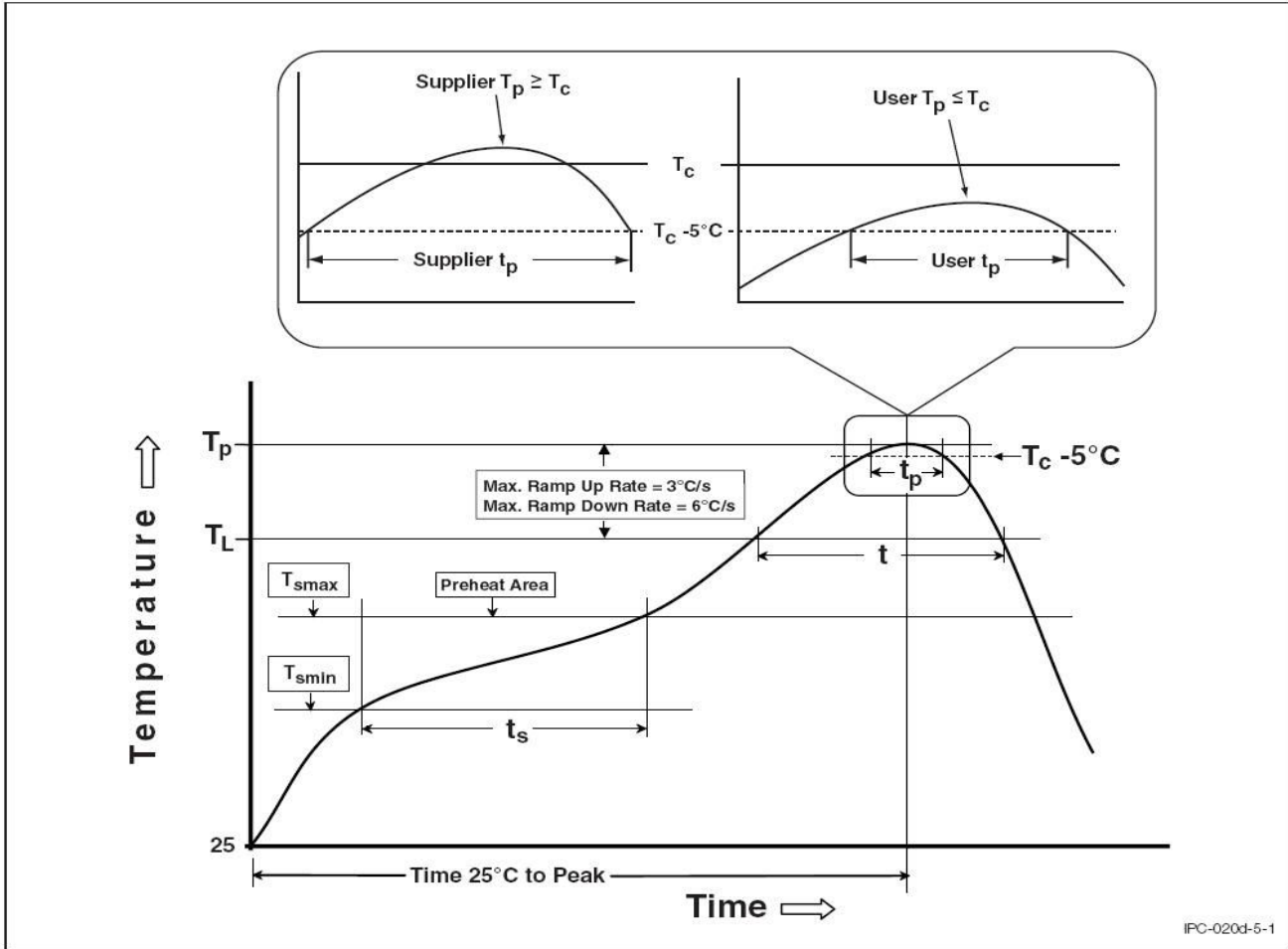
<p>TD1:1 (CD=3! -</p>	
<p>TD : , company Abbr#</p> <p>101X : *an" 60J1J?J=J!J(J5J3J7J<8</p> <p>K : Tape and *eel Option 6T1JT?8</p> <p>G : Green</p> <p>) :)D1 Option 6) or 4one8</p>	

PACKING ANTIFAKE

Option	E&antit<	E&antit< F Inner 1o?	E&antit< F Outer 1o?
T1	=000 2nits! *eel	= *eels!Anner bo-	(Anner bo-JOuter bo- D ! (" 2nits
T?	=000 2nits! *eel	= *eels!Anner bo-	(Anner bo-JOuter bo- D ! (" 2nits

)EF#OB INFO)MATION

)EF#OB P)OFI#E



Profile Feature	Sn3P1 Assembly Profile	P13Free Assembly Profile
Temperature +in# 6T _{smin}	100	1 (0/ ,
Temperature +a-# 6T _{smax}	1 (0	?00/ ,
Time 6ts from 6T _{smin} to T _{smax}	50.1?0 seconds	50.1?0 seconds
* amp.up * ate 6t _L to t _s	=/ , Jsecond ma-#	=/ , Jsecond ma-#
Liquidous Temperature 6TL	17=/ ,	?13/ ,
Time 6t _L + aintained Abo&e 6TL	50 : 1 (0 seconds	50 : 1 (0 seconds
ea" ;ody ac"age Temperature	?=(/ , L0/ , J.(/ ,	?50/ , L0/ , J.(/ ,
Time 6t _s within (/ , of ?50/ ,	?0 seconds	=0 seconds
* amp.down * ate 6T _s to TL	5/ , Jsecond ma-	5/ , Jsecond ma-
Time ?(/ , to ea" Temperature	5 minutes ma-#	7 minutes ma-#



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